# Thermally driven out-of-equilibrium Kondo system

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**-X**-

- Thermoelectric transport
- Kondo effect in quantum dots
- Thermally driven single dot
- Theoretical approaches
- Results(I)



- Thermally driven two impurity Kondo system
- Theoretical model
- Results (II)
- Conclusions



First experimental evidences of Kondo effect

D. Goldhaber-Gordon *et al.*, *Nature* **391**, 156 (1998).
S. M. Cronenwett, T. H. Oosterkamp, L. P. Kouwenhoven, *Science* **281**, 540 (1998).
J. Schmid, J. Weis, K. Eberl, K. v. Klitzing, *Physica B* **256**, 182 (1998).





Circuit heat generation is one key limiting factor for scaling device speed



Waste heat recovery: typically 30-40 % efficiency for heatengines, waste heat 60%

THERMOELECTRICS is recognized as a potentially transformative energy conversion technology: heat is directly converted into electricity and vice versa







## Thermolectric transport<sup>\*</sup>



Large thermal gradients large as 13K/mV R. Venkatasubramanian et al., Nature 413, 597 (2001)

Rectification effects due to interactions Thermopower changes sign, A.A.M. Staring et al., EPL 22, 57 (1993)







## Thermolectric transport<sup>\*</sup>



Nanosystems exhibit REMARKABLE THERMOELECTRIC properties

Specially when transport properties depend very much on **energy** as in the case of **quantum dots** 





# Quantum Dots

#### Quantum dot: 0D system



## Coulomb blockade phenomena





#### L. P. Kouwenhoven, Science 1997



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Coulomb energy E<sub>c</sub>=q<sup>2</sup>/2C





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Resistance Minimum in Dilute Magnetic Alloys" Progress of Theoretical Physics 32 (1964) 37 J. Kondo





Temperature Kondo: characteristic energy scale





## Kondo effect in quantum dots 关

L.I. Glazman and M.E. Raikh JETP Lett. 47, 452(1988), T.K..Ng and P.A. Lee, Phys. Rev. Lett. 61, 1768 (1988)



The resulting correlated motion gives rise to a Kondo resonance in the quasiparticle density of states at the Fermi energy Due to this resonance the transmission through the quantum dot is perfect, the socalled "unitary limit"







**SPIN KONDO** 

Unitary limit in the even valleys when the temperature is lowered

Appearance of the Zero Bias Anomaly in the Coulomb diamond





Δ mΚ 2 (c) IV 693 G (e<sup>2</sup>/h) 301 82 32 0 10 e²/h 0.5 (d)  $V_{sd}(mV)$ 2 0 0.5 3.4 3.6 3.2 -3 2.8 2.6 (V)

PHYSICAL REVIEW B 84 , 245316 (2011)





## Single Quantum Dot case







Kondo Hamiltonian  $\mathcal{H}_{K} = \mathcal{H}_{0} + \mathcal{H}_{1}$ 

$$\mathcal{H}_{0} = \sum_{\alpha k\sigma} \varepsilon_{\alpha k} C_{\alpha k\sigma}^{\dagger} C_{\alpha k\sigma} \quad \mathcal{H}_{1} = \sum_{\alpha k\sigma\beta qs} \mathcal{J}_{\alpha\beta}(t) x_{\sigma s} C_{\alpha k\sigma}^{\dagger} C_{\beta qs}$$

$$x_{\sigma s} = \delta_{\sigma s} / 4 + \hat{S}_l s_{\sigma s}^l$$

$$\mathcal{J}_{\alpha\beta}(t) = \mathcal{J}_{\alpha\beta}^{(0)} \exp\left(-\frac{ie}{\hbar}[V_{\alpha} - V_{\beta}]t\right),$$

Localized and delocalized electrons: spin operators

 $\mathcal{J}_{\alpha\beta}^{(0)} = -\mathcal{V}_{\alpha}\mathcal{V}_{\beta}U/[\varepsilon_d(U+\varepsilon_d)]$ 

 $S_l, l = x, y, z$ 



#### Poor man scaling procedure





#### Anderson Hamiltonian

*<b>FISC* 

$$\mathcal{H} = \mathcal{H}_{\text{leads}} + \mathcal{H}_{\text{dot}} + \mathcal{H}_{\text{tun}}$$
$$\mathcal{H}_{\text{leads}} = \sum_{\alpha k\sigma} \varepsilon_{\alpha k} C^{\dagger}_{\alpha k\sigma} C_{\alpha k\sigma}$$
$$\mathcal{H}_{\text{dot}} = \sum_{\alpha k\sigma} \varepsilon_{d} d^{\dagger}_{\sigma} d_{\sigma} + U d^{\dagger}_{\uparrow} d_{\uparrow} d^{\dagger}_{\downarrow} d_{\downarrow}$$
$$\mathcal{H}_{\text{tun}} = \sum_{\alpha k\sigma} \mathcal{V}_{\alpha k} C^{\dagger}_{\alpha k\sigma} d_{\sigma} + \text{H.c}$$

Mean-field approach

$$\langle b \rangle = \tilde{b}$$

$$\sum_{\alpha k\sigma} \tilde{\mathcal{V}}_{\alpha k} G^{<}_{f\sigma,\alpha k\sigma}(t,t) = -i N \lambda |\tilde{b}|^2 / \hbar$$

$$\sum G^{<}_{f\sigma,f\sigma}(t,t) = i(1-N|\tilde{b}|^2)/\hbar$$

$$U \longrightarrow \infty$$
  

$$d_{\sigma} = b^{\dagger} f_{\sigma}$$
  
pseudofermion operator  $f_{\sigma}$   
boson field operator  $b^{\dagger}$   

$$\mathcal{H}_{Lag} = \lambda \left( b^{\dagger} b + \sum f_{\sigma}^{\dagger} f_{\sigma} - 1 \right)$$
  

$$\mathcal{H}_{tun} = \sum_{\alpha k \sigma} \mathcal{V}_{\alpha k} C_{\alpha k \sigma}^{\dagger} b^{\dagger} f_{\sigma} + \text{H.c.}$$
  

$$\mathcal{V}_{Lk} \qquad \mathcal{V}_{Rk} \qquad \mathcal{V}_{Rk}$$

 $G^{<}_{f\sigma,\alpha k\sigma}(t,t') = -(i/\hbar) \langle C^{\dagger}_{\alpha k\sigma}(t') f_{\sigma}(t) \rangle$ 





## Mean field parameters





**\*** 

## **Electrically driven**

Thermally driven



FIG. 3. Position of the SBMET (a) renormalized energy level  $\tilde{s}_d$  and (b) width  $\tilde{\Gamma}$  as a function of the applied voltage for different dot level positions. The case  $s_d = -3.5\Gamma$  agrees with the analytical result given by Eq. (24). Parameters:  $D = 100\Gamma$ ,  $k_BT = 0$ , and  $\Gamma_L = \Gamma_R = \Gamma/2$ .

Bias voltage induced Kondo splitting



FIG. 4. (a) Renormalized dot gate position  $\tilde{s}_d$  and (b) resonance width  $\tilde{\Gamma}$  as a function of the thermal bias  $\theta$  for different  $s_d$  values within SBMFT. (Inset) Resonance width versus the thermal bias from a numerical calculation (solid line) and from the analytical expression given by Eq. (27) (dashed line) for  $s_d = -3.5\Gamma$ . Parameters: D =100 $\Gamma$ ,  $k_B T = 0$ , and  $\Gamma_L = \Gamma_R = \Gamma/2$ .

Thermal bias Kondo width quenching



#### Electric, and Thermoelectrical transport 🔸

$$I = -\frac{e}{h} \int_{-\infty}^{\infty} d\omega \sum_{\sigma} \frac{4\Gamma_L \Gamma_R}{\Gamma} \mathrm{Im} \left[ G_{\sigma,\sigma}^r(\omega) \right] [f_L(\omega) - f_R(\omega)].$$

$$L_2 = \frac{4\pi^2 e k_B^2}{3h} \tilde{\Gamma}_L \tilde{\Gamma}_R \frac{\tilde{\varepsilon}_d}{\tilde{\varepsilon}_d^2 + \tilde{\Gamma}^2}$$

#### **Electrically driven**

Thermally driven



FIG. 5. Current-voltage characteristics of a single level quantum dot in the Kondo regime using slave-boson mean-field theory for different values of the gate voltage (level position). (Inset) Differential conductance of the quantum dot as a function of the applied voltage. Parameters:  $D = 100\Gamma$ ,  $k_BT = 0$ , and  $\Gamma_L = \Gamma_R = \Gamma/2$ .

#### Unitary limit in the deep Kondo regime



FIG. 6. Thermocurrent as a function the thermal gradient  $\theta$  of a single level quantum dot in the Kondo regime using slave-boson mean-field theory for different values of the dot gate position. Inset: thermoelectric conductance as a function of the thermal bias for the same dot gate positions. Parameters:  $D = 100\Gamma$ ,  $k_BT = 0$ , and  $\Gamma_L = \Gamma_R = \Gamma/2$ .

Larger thermocurrent when charge fluctuations are present



Equation of motion technique



### By using EOM tenchique the dot Green function reads

$$G_{\sigma,\sigma}^{r}(\omega) = \frac{1 - \langle \tilde{n}_{\bar{\sigma}} \rangle}{\omega - \varepsilon_{d} - \Sigma_{0} + U\Sigma_{1} / [\omega - \varepsilon_{d} - U - \Sigma_{0} - \Sigma_{3}]} + \frac{\langle \tilde{n}_{\bar{\sigma}} \rangle}{\omega - \varepsilon_{d} - \Sigma_{0} - U - U\Sigma_{2} / [\omega - \varepsilon_{d} - \Sigma_{0} - \Sigma_{3}]}$$
$$T_{K0} \approx \sqrt{2\Gamma U} \exp\left[-\frac{\pi |\varepsilon_{d}| (U + \varepsilon_{d})}{2\Gamma U}\right]$$

Self-energies are determined and the dot occupation is computed self-consistently

$$\Sigma_0 \quad \Sigma_1 \quad \Sigma_2 \quad \Sigma_3 \mid \langle \tilde{n}_{\bar{\sigma}} \rangle$$

O. Entin-Wohlman, et at., Phys. Rev. B 71 035333 (2005)



## Finite-U Equation of motion technique

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## Equilibrium spectral density



FIG. 8. Finite-*U* quantum dot spectral density at equilibrium for different background temperatures. Parameters:  $\varepsilon_d = -3.5\Gamma$ ,  $D = 100\Gamma$ , and  $U = 20\Gamma$ . (Insets) (a) Detail of the dot spectral density of states around the Fermi energy. (b) Height of the Kondo peak as a function of the background temperature.



## Electrical and thermal driven cases: spectral density



FIG. 7. (a) Nonequilibrium infinite-U quantum dot spectral density of states for different eV values. (Inset) Detail of the density of states around the Fermi energy ( $\varepsilon_F = 0$ ). (b) Nonequilibrium infinite-U quantum dot spectral density of states for different thermal gradients. The background temperature is set at  $T = 0.024T_{K0}$ . (Inset) Detail of the density of states around the Fermi energy ( $\varepsilon_F = 0$ ). Parameters:  $\varepsilon_d = -3.5\Gamma$ ,  $D = 100\Gamma$ , and  $T = 0.024T_{K0}$ . The Kondo peak splits with the bias voltage

# Kondo peak is quenched with the thermal bias

Artifact of the model: the cold reservoirs always yields a Kondo singularity even for large thermal gradients



## Finite U electric, and thermoelectrical transport \*

## **Electrical current**

#### **Electrically driven**

Thermally driven



FIG. 9. *I-V* characteristics at different dot level positions. (Inset) Differential electric condutance vs voltage bias for the given values of the energy level. Parameters:  $D = 100\Gamma$ ,  $k_BT = 0.0001\Gamma$ ,  $U = 20\Gamma$ , and  $\Gamma_L = \Gamma_R = \Gamma/2$ .

Steps at the dot resonances: mean-field peaks and Kondo singularity



FIG. 10. Thermocurrent vs the thermal gradient for different dot gate positions. (Inset) Detail of the thermocurrent at low thermal gradients. Parameters:  $U = 20\Gamma$ ,  $D = 100\Gamma$ ,  $k_BT = 0.01\Gamma$ , and  $\Gamma_L = \Gamma_R = \Gamma/2$ .

Non trivial zero at the spin and charge fluctuation energy scales



#### Nontrivial zeros at the thermoelectrical current in the finite U case



A e-like dominant Kondo peak
B h-like dominant Kondo peak and
e-like contribution from the mean
field peak
C e-like dominant from the second
mean field peak, the others are h-like

The different electron-like and hole-like contributions of the Kondo and mean-field peaks leads to the appearance of the nontrivial zeros in the thermoelectrical current when the thermal bias increases









- A single quantum dot is considered in the Kondo regime.
- The Kondo effect is quenched with the thermal bias: results from perturbation theory, SBMFT, and EOM



#### Transport

Thermocurrent

- Nonlinear behavior
- Appearance of nontrivial zeros



Double Quantum Dot case

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## Double Quantum Dot case





#### The Kondo Effect in an Artificial Quantum Dot Molecule

H. Jeong, A. M. Chang and M. R. Melloch

Science 293 (5538), 2221-2223. DOI: 10.1126/science.1063182



Hybridization of Kondo singlets into a coherent superposition of Kondo states Bonding-Antibonding Kondo states!

R. Aguado, D. C. Langreth, *Phys. Rev. Lett.* 85, 1946 R. Aguado, D. C. Langreth, *Phys. Rev. B* 67, 245307 (2003) (2000).











N. J. Craig, et al., Science 304, 565 (2004)





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Coherent control of quantum dot spins by a nonlocal RKKY-like interaction

$$\mathcal{H}_J = J\hat{S}_L \cdot \hat{S}_R$$



#### Slave boson mean field description 关

R. López et al., Physical review letters 89, 136802 (2003)



Serial QDs: Crossover from the Kondo phase to the antiferromagnetic phase













### Temperature driven case for the Kondo temperature 🔭



$$T_{K\alpha} \equiv \tilde{\Gamma}_{\alpha}(\theta)$$

Renormalized width determines the role of the Kondo effect

#### Three different regimes depending on

t and  $\Gamma = \Gamma_L + \Gamma_R$ 

Strong coupling

 $t > \Gamma$  $\Gamma_{\alpha}$  behave similarly Bonding and antibonding states











ratio

$$I = \frac{e}{h} \int d\omega [f_L(\omega) - f_R(\omega)] \mathcal{T}(\omega)$$

$$Transmission function$$

$$\mathcal{T}(\omega) = 4 \sum_{\sigma} \tilde{\Gamma}_L \tilde{\Gamma}_R |G_{fL\sigma,fR\sigma}^r|^2$$

$$\mu_{\alpha} = \varepsilon_F$$

$$\theta = T_L - T_R$$

$$f(u) = 4 \sum_{\sigma} (1 - \frac{1}{2}) \int_{\sigma}^{\sigma} (1 - \frac{1}{2})$$



## Antiferromagnetic Kondo crossover

Case of relevant antiferromagnetic interactions. 
$${\cal H}_J=J\hat{S}_L\cdot\hat{S}_R$$

A crossover can occur between the Kondo singlet and the dot-dot AF singlet.



P. Simon, R. López, and Y. Oreg, Phys. Rev. Lett. 94, 086602 (2005)







- A serially-coupled double quantum dot is considered in the Kondo regime.
- Depending on  $t/\Gamma$ , one can identify different regimes:
  - Weakly coupled regime
  - Intermediate coupled regime

#### Transport

- Heat current
  - $lacksim ext{Vanishing at large}^{ heta}$
  - Thermal diode behavior.
- Thermocurrent
  - Nonlinear behavior.

#### **Critical value**

Tunneling modifies the critical value of the crossover.

#### Phys. Rev. Lett. 121, 096801



1.0

10-1

 $10^{0}$ 

 $\theta/T_K$ 

 $10^{1}$ 

 $10^{2}$ 

 $I(\theta) (e\Gamma/h)$ 







# **THANK YOU**

for your attention







